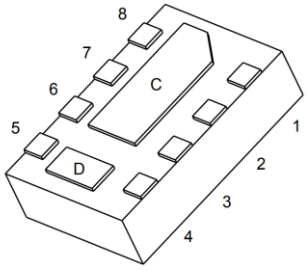
WT2NP42

PNP Silicon Transistor with N-Channel MOSFET

Features

- N-Channel MOSFET：
  V_{DS}= 20V, I_D = 1A
  $R_{DS(on)}$ < 250mΩ @ V_{GS} = 4.5V
  $R_{DS(on)}$ < 390mΩ @ V_{GS} = 2.5V
- PNP Power Transistor:
  V_{CEO}= -25V, I_C= -3A

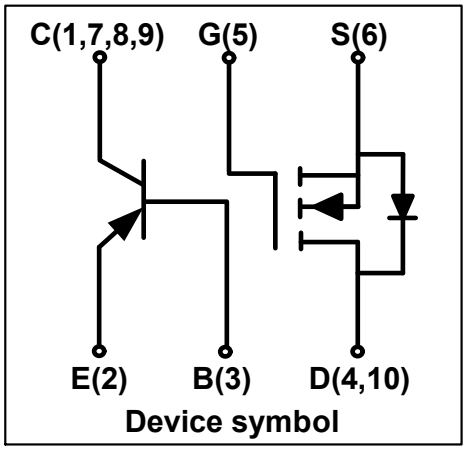


DFN3020-8L

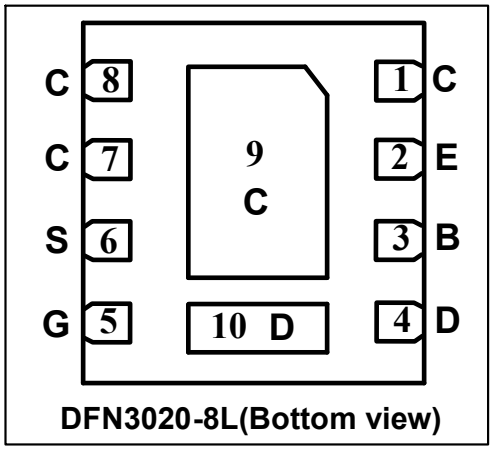
Mechanical Characteristics

- DFN3020-8L Package
- Marking : Making Code
- RoHS Compliant & HF

Schematic & PIN Configuration



Device symbol



DFN3020-8L(Bottom view)

Absolute Maximum Rating (PNP Transistor) (Tamb=25°C unless otherwise noted)

Rating	Symbol	Value	Units
Collector-Base Voltage	V_{CBO}	-25	V
Collector-Emitter Voltage	V_{CEO}	-25	V
Emitter-Base Voltage	V_{EBO}	-7.5	V
Collector Current-Continuous	I_C	-3	A

Absolute Maximum Rating (N-Channel MOSFET) (Tamb=25°C unless otherwise noted)

Rating	Symbol	Value	Units
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±10	V
Continuous Drain Current	I_D	1	A
Pulsed Drain Current	I_{DM}	4	A

Absolute Maximum Rating (Tamb=25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Power Dissipation	P_D	2.5	W
Operating Junction Temperature	T_J	–55 to 150	°C
Storage Temperature	T_{STG}	–55 to 150	°C
Lead Temperature	T_L	260	°C
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	50	°C/W

Electrical Characteristics of PNP Transistor (Tamb=25°C unless otherwise noted)

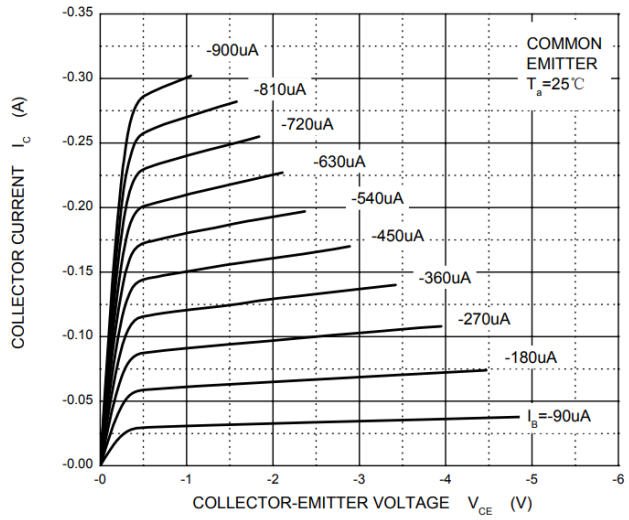
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C = -100μA, I_E = 0	-25	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C = -10mA, I_B = 0	-25	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E = -100μA, I_C = 0	-7.5	-	-	V
Collector Cut-off Current	I_{CBO}	V_{CB} = -20V, I_E = 0	-	-	-25	nA
Emitter Cut-off Current	I_{EBO}	V_{EB} = -6V, I_C = 0	-	-	-25	nA
DC Current Gain	$h_{FE(1)}$	V_{CE} = -2V, I_C = -0.01A	300	-	-	
	$h_{FE(2)}$	V_{CE} = -2V, I_C = -0.1A	300	-	-	
	$h_{FE(3)}$	V_{CE} = -2V, I_C = -2A	150	-	-	
	$h_{FE(4)}$	V_{CE} = -2V, I_C = -6A	15	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = -0.1A, I_B = -10mA	-	-	-30	mV
		I_C = -1A, I_B = -20mA	-	-	-220	
		I_C = -1.5A, I_B = -50mA	-	-	-250	
		I_C = -2.5A, I_B = -150mA	-	-	-350	
		I_C = -3.5A, I_B = -350mA	-	-	-380	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C = -3.5A, I_B = -350mA	-	-	-1.075	V
Base-Emitter Voltage	$V_{BE(on)}$	V_{CE} = -2V, I_C = -3.5A	-	-	-0.95	V
Transition Frequency	f_T	V_{CE} = -10V, I_C = -50mA f=100MHz	150	-	-	MHz

Electrical Characteristics of N-Channel MOSFET (Tamb=25°C unless otherwise noted)

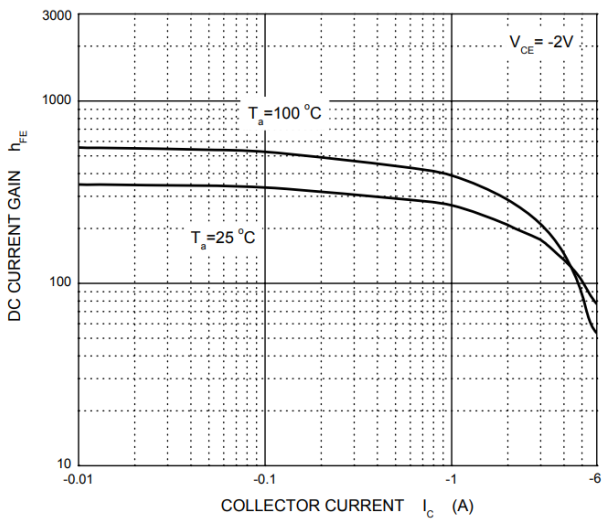
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D = 250μA	20	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} =20V, V_{GS} = 0V	-	-	1	μA
Gate-body Leakage Current	I_{GSS}	V_{DS} = 0V, V_{GS} = ±10V	-	-	±10	μA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250μA	0.35	0.75	1.1	V
Drain-Source on-State Resistance	$R_{DS(on)}$	V_{GS} = 4.5V, I_D = 0.65A	-	0.15	0.25	Ω
		V_{GS} = 2.5V, I_D = 0.55A	-	0.2	0.39	
		V_{GS} = 1.8V, I_D = 0.45A	-	0.3	-	
Dynamic Characteristics						
Input Capacitance	C_{iss}	V_{GS} = 0V, V_{DS} = 10V, f = 1MHz	-	58	-	pF
Output Capacitance	C_{oss}		-	14.5	-	
Reverse Transfer Capacitance	C_{rss}		-	9	-	
Switching Characteristics						
Total Gate Charge	Q_g	V_{GS} = 4.5V,V_{DS} = 10V, I_D = 0.65A	-	1.1	-	nC
Gate-Source Charge	Q_{gs}		-	0.27	-	
Gate-Drain Charge	Q_{gd}		-	0.25	-	
Turn-on Delay Time	$t_{d(on)}$	V_{GS} = 4.5V, V_{DD} = 10V, I_D = 0.65A, R_G= 3Ω	-	3.3	-	ns
Turn-on Rise Time	t_r		-	1.1	-	
Turn-off Delay Time	$t_{d(off)}$		-	16.2	-	
Turn- off Fall Time	t_f		-	8.4	-	
Source-Drain Diode Characteristics						
Body Diode Voltage	V_{SD}	I_S= 0.5A, V_{GS} = 0V	-	-	1.2	V
Continuous Source Current	I_S		-	-	0.75	A

Typical Characteristics: PNP Silicon Transistor

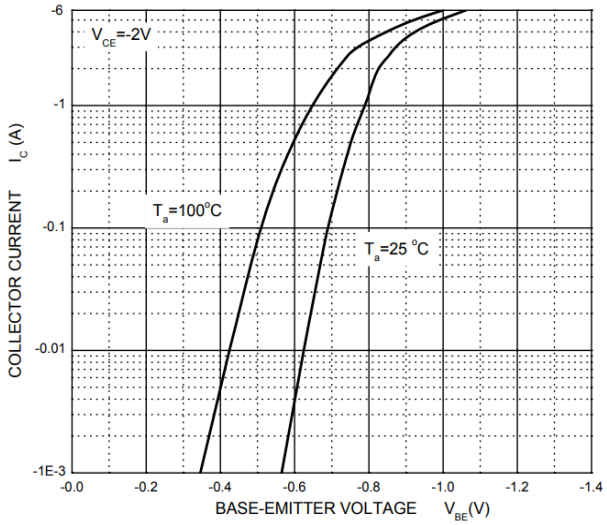
Static Characteristic



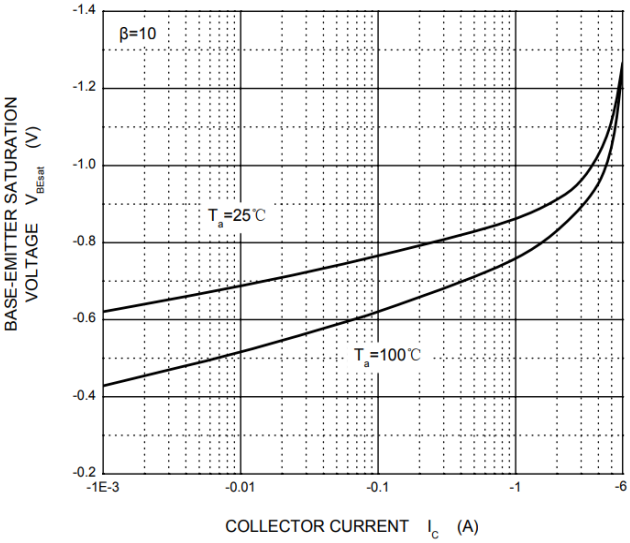
h_{FE} —— I_C



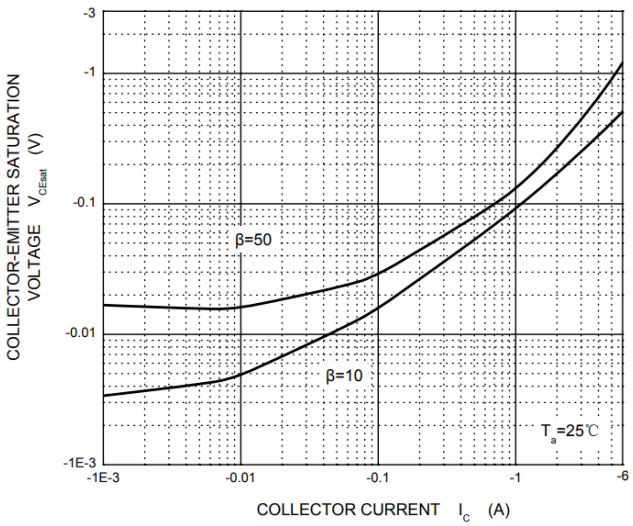
I_C —— V_{BE}



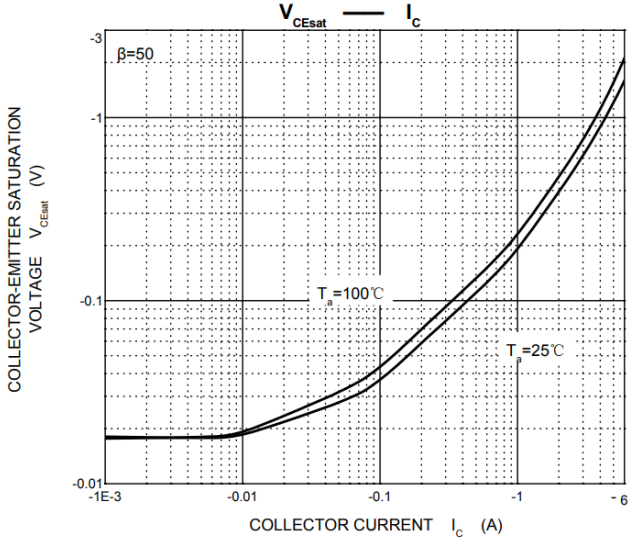
V_{BEsat} —— I_C

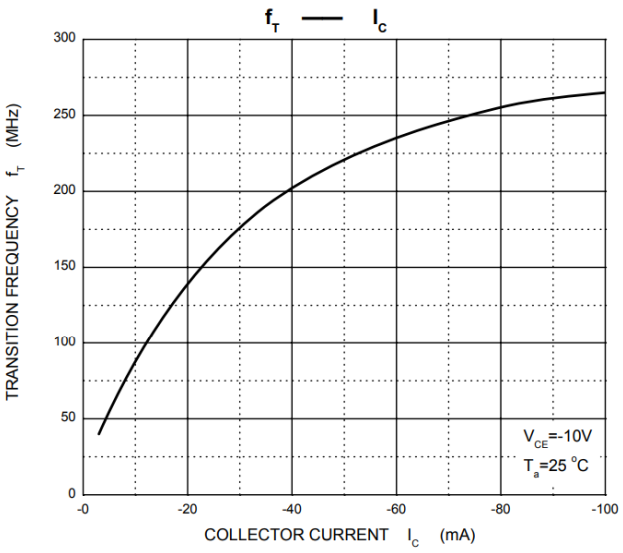


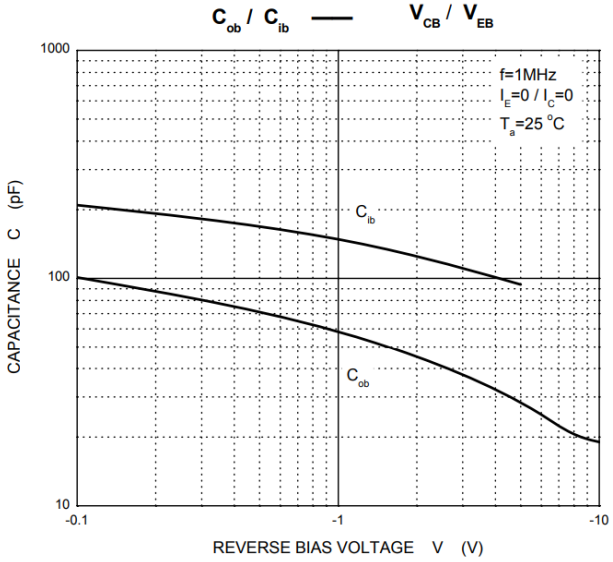
V_{CEsat} —— I_C



V_{CEsat} —— I_C




f_T —— I_C
TRANSITION FREQUENCY f_T (MHz)
300
250
200
150
100
50
0
-0
-20
-40
-60
-80
-100
COLLECTOR CURRENT I_C (mA)
V_{CE}=-10V
T_a=25 °C


C_{ob} / C_{ib} —— V_{CB} / V_{EB}
CAPACITANCE C (pF)
1000
100
10
-0.1
-1
-10
REVERSE BIAS VOLTAGE V (V)
f=1MHz
I_E=0 / I_C=0
T_a=25 °C
C_{ib}
C_{ob}

Typical Characteristics: N-Channel MOSFET

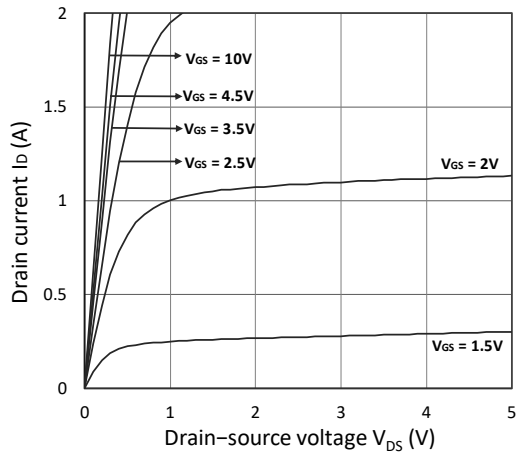


Figure 1. Output Characteristics

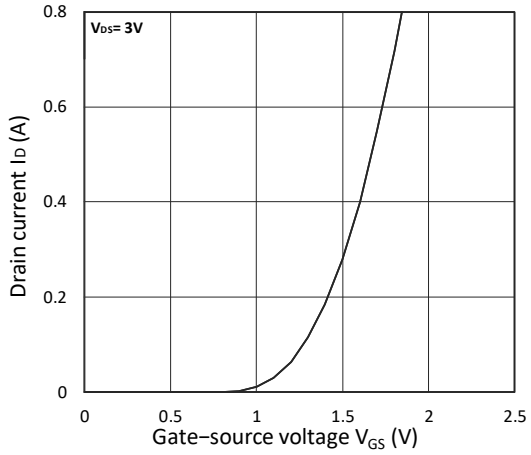


Figure 2. Transfer Characteristics

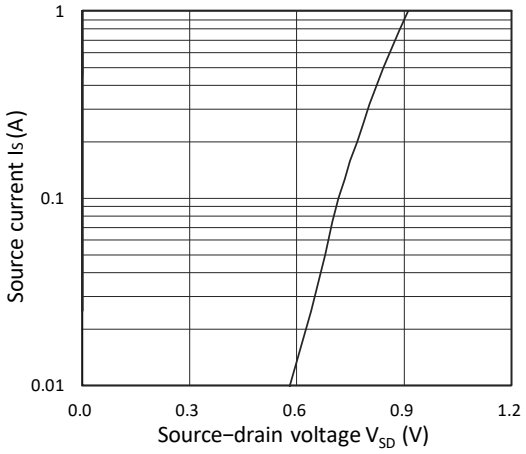


Figure 3. Forward Characteristics of Reverse

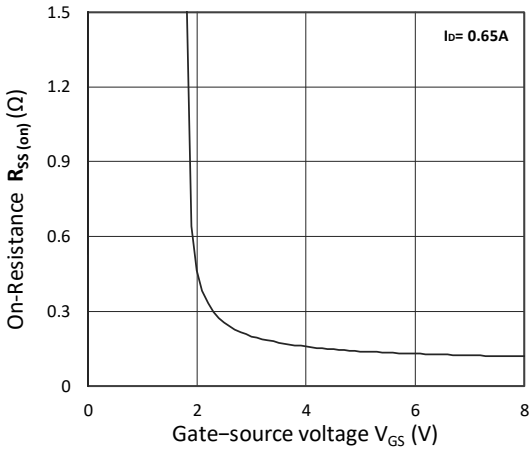


Figure 4. $R_{DS(ON)}$ vs. V_{GS}

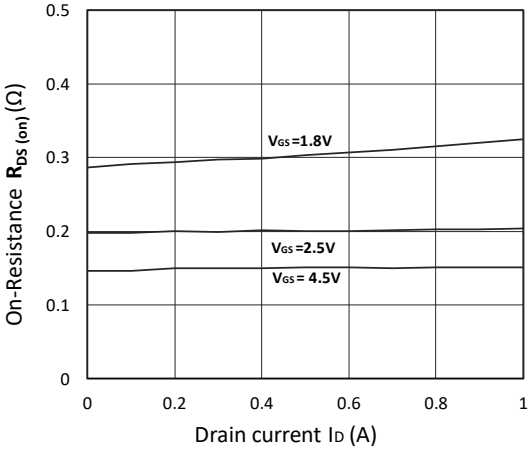


Figure 5. $R_{DS(ON)}$ vs. I_D

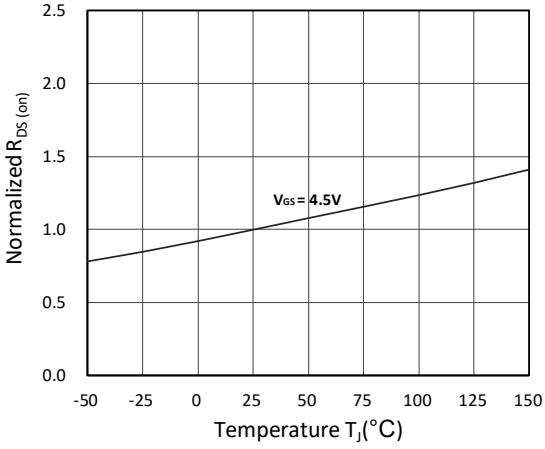


Figure 6. Normalized $R_{DS(on)}$ vs. Temperature

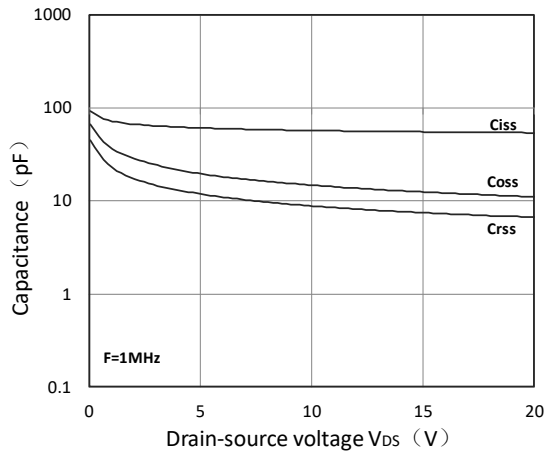


Figure 7. Capacitance Characteristics

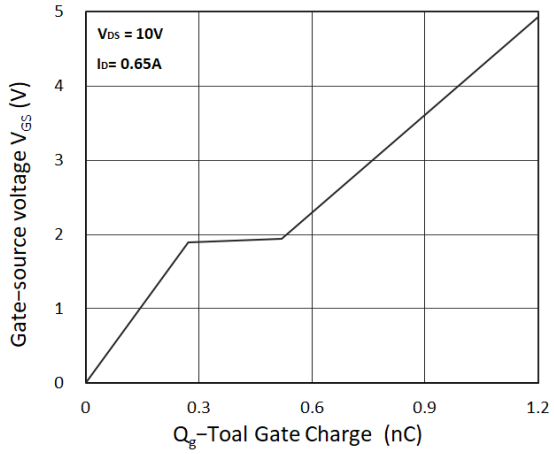
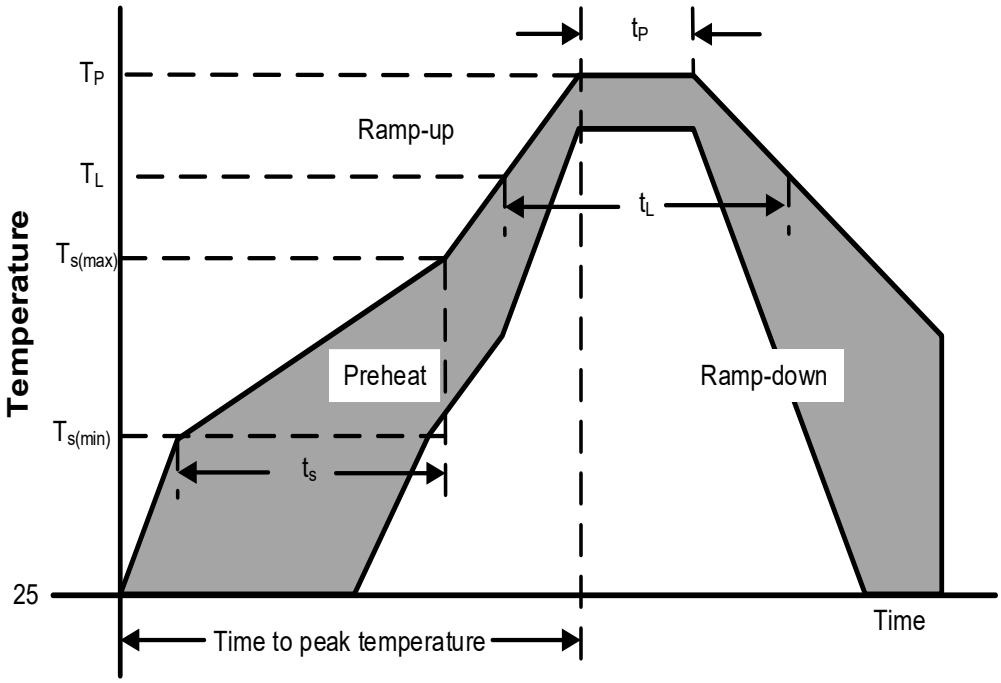


Figure 8. Gate Charge Characteristics

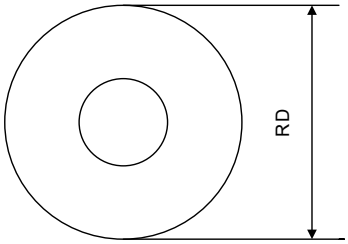
Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (ts)	60 – 190 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L——Ramp-up Rate		5°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		260+0/-5 °C
Time within actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C

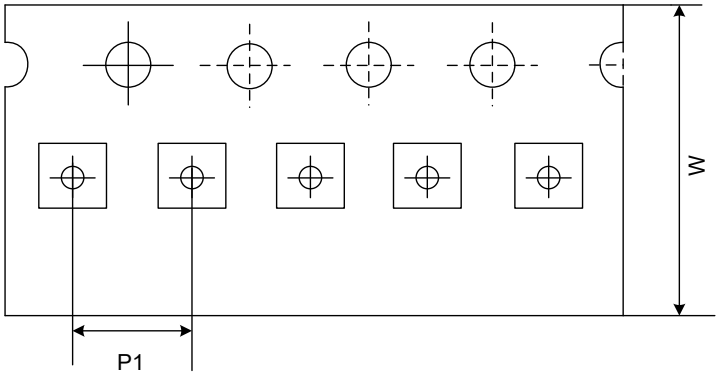


Tape And Reel Information

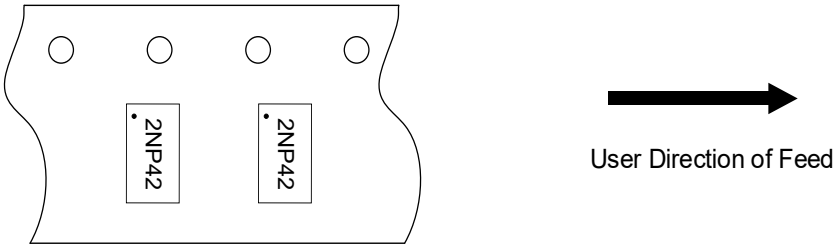
Reel Dimensions



Tape Dimensions

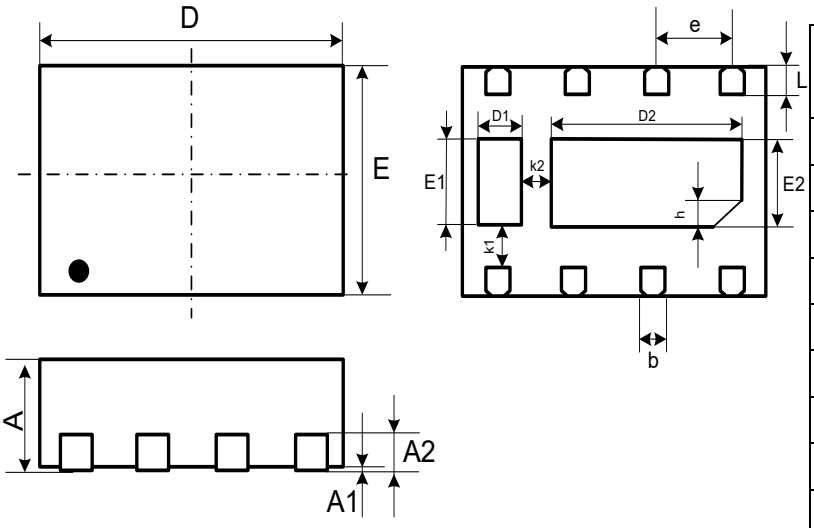


Quadrant Assignments For PIN1 Orientation In Tape



RD	Reel Dimensions	7 inch
W	Overall width of the carrier tape	8 mm
P1	Pitch between successive cavity centers	4 mm

Mechanical Dimensions for DFN3020-8L



SYMBOL	MILLMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
b	0.25	0.30	0.35
A2		0.203 BSC	
D	2.90	3.00	3.10
E	1.90	2.00	2.10
E1	0.75	0.80	0.85
E2	0.75	0.80	0.85
D1	0.35	0.40	0.45
D2	1.75	1.80	1.85
e		0.65 REF	
L	0.25	0.30	0.35
h		0.42 BSC	
k1	0.30	0.35	0.40
k2	0.25	0.30	0.35

Marking Codes

Part Number	WT2NP42
Marking Code	2NP42

Package Information

Qty：3k/Reel

CONTACT INFORMATION

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WAYON website: **http://www.way-on.com**
For additional information, please contact your local Sales Representative.

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Product Specification Statement

1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

3. WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

4. Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

5. The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

6. Users should also comply with relevant laws, regulations, policies, and standards when using the product specification. Users are responsible for the risks and liabilities arising from the use of the product specification and must ensure that it is not used for illegal purposes. Additionally, users should respect the intellectual property rights related to the product specification and refrain from infringing upon any third-party legal rights. WAYON shall assume no responsibility for any disputes or controversies arising from the above-mentioned issues in any form.